

## **PESDLC2FD5VUH**

# **Uni-directional 5V Low Capacitance ESD Protector**

#### Description

The PESDLC2FD5VUH ESD protector is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs.

#### Feature

- Low capacitance 1.0pF
- DFN1006-2L package
- Replacement for MLV(0402)
- Unidirectional configurations
- Response time is typically < 1 ns</p>
- Protect one I/O or power line
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±20KV (air), ±20KV (contact);
  IEC 61000-4-4 (EFT) 40A (5/50ns)

#### **Applications**

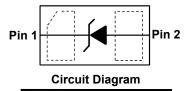
- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 player

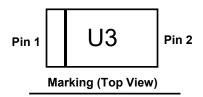
#### **Mechanical Characteristics**

- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- DFN1006-2L without plating



#### DFN1006-2L(Bottom View)



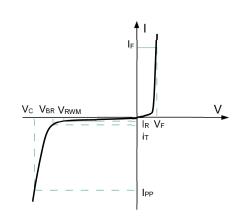


# Low Capacitance ESD Protector

### **Electronics Parameter**

Symbol	Parameter		
VRWM	Peak Reverse Working Voltage		
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>		
VBR	Breakdown Voltage @ I⊤		
Ιτ	Test Current		
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P <sub>PP</sub>	Peak Pulse Power		
CJ	Junction Capacitance		
lF	Forward Current		
VF	Forward Voltage @ I <sub>F</sub>		

### PESDLC2FD5VUH



## Electrical characteristics per line@25°C( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	VRWM				5.0	V
Breakdown Voltage	V <sub>BR</sub>	lt=1mA	6.0	7.0	8.0	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =5V			1.0	μA
Forward Voltage	VF	I <sub>F</sub> =10mA		0.8	1.25	V
Clamping Voltage	Vc	I <sub>PP</sub> =1.0A t <sub>P</sub> = 8/20µS		9.0	11.0	V
Clamping Voltage	Vc	I <sub>PP</sub> =5.0A t <sub>P</sub> = 8/20μS		11.5	13.0	V
Clamping Voltage	Vc	I <sub>PP</sub> =8.0A t <sub>P</sub> = 8/20µS		15.0	17.0	V
Junction Capacitance	Cj	V <sub>R</sub> =0V f = 1MHz		1.1	1.3	pF

## Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t <sub>p</sub> =8/20µs)	P <sub>pp</sub>	130	W
Lead Soldering Temperature	ΤL	260(10 sec)	°C
Operating Temperature	TJ	-55 to 125	°C
Storage Temperature	Тѕтс	-55 to 150	°C

# Low Capacitance ESD Protector

#### PESDLC2FD5VUH

## **Typical Characteristics**

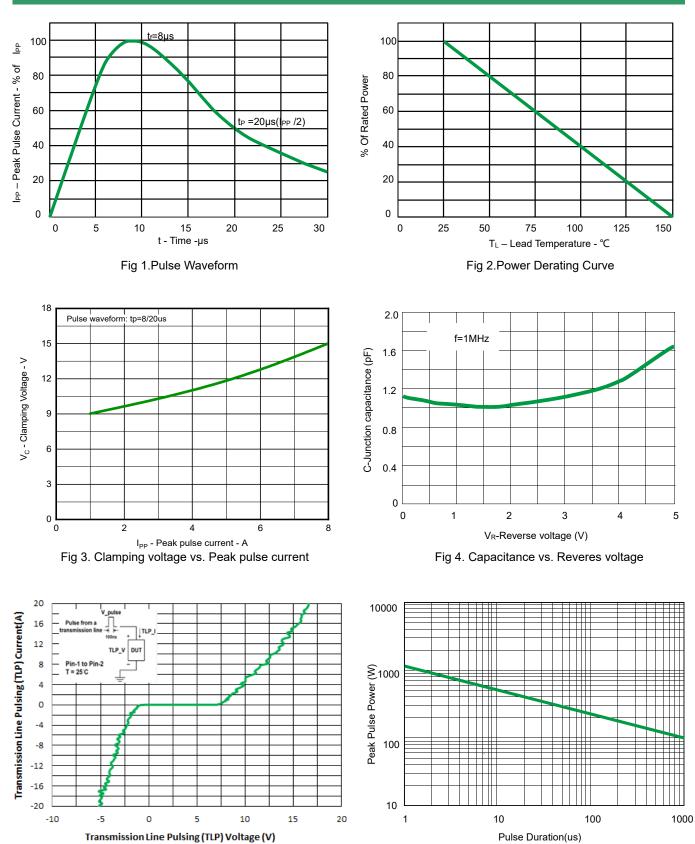


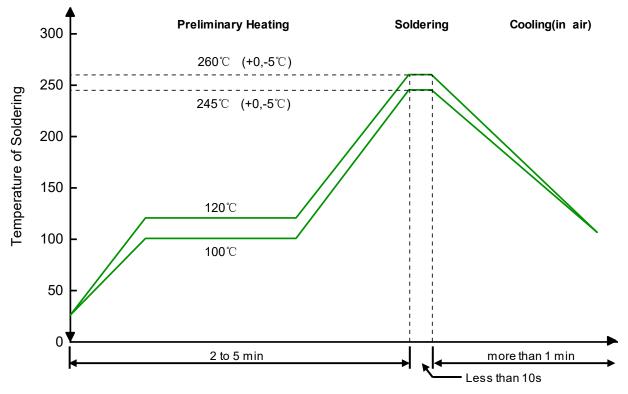
Fig 5. TLP Measurement

Fig 6. Non Repetitive Peak Pulse Power vs. Pulse time

### PESDLC2FD5VUH

## Low Capacitance ESD Protector

#### **Solder Reflow Recommendation**



Remark: Pb free for 260°C; Pb for 245°C.

### PCB Design

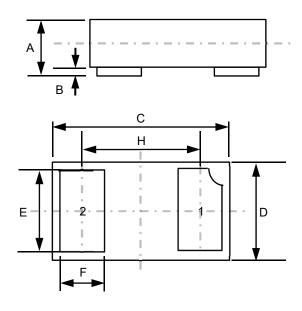
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

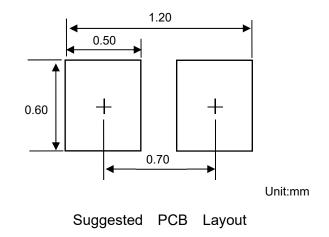
## PESDLC2FD5VUH

# Low Capacitance ESD Protector

# Product dimension (DFN1006-2L)



Dim	Millimeters			
	MIN	NOM	МАХ	
А	0.40	0.45	0.498	
В	0.00	0.02	0.05	
С	0.95	1.00	1.05	
D	0.55	0.60	0.65	
E	0.45	0.50	0.55	
F	0.20	0.25	0.30	
н	0.65BSC			



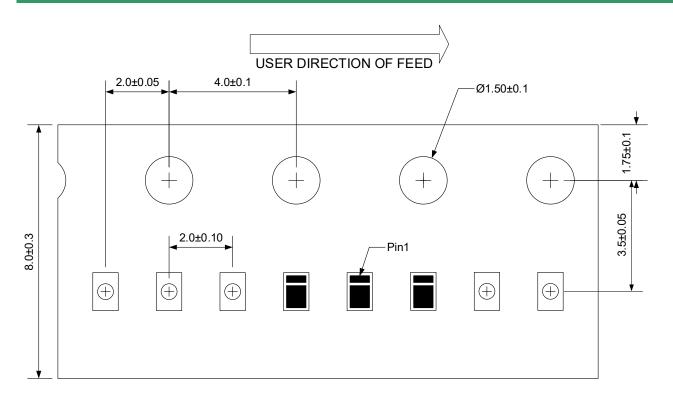
## Ordering information

Device	Package	Reel	Shipping
PESDLC2FD5VUH	DFN1006-2L	7"	10000 / Tape & Reel

# Low Capacitance ESD Protector

### PESDLC2FD5VUH

## Load with information



#### Unit:mm

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